

## **ISC Silicon NPN Power Transistor**

2SC5552

### **DESCRIPTION**

- · High Breakdown Voltage
- · High Switching Speed
- Low Saturation Voltage
- · Wide area of safe operation
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

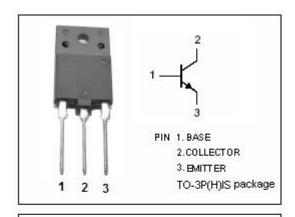


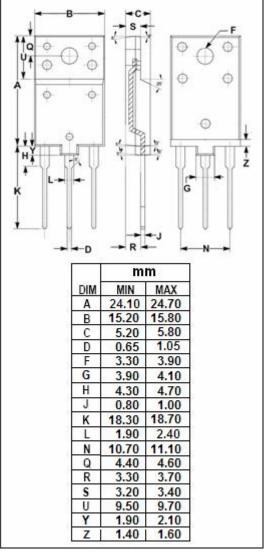
### **APPLICATIONS**

· Character display horizontal deflection output

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	1700	V
V <sub>CEO</sub>	Collector-Emitter Voltage 600		
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
Ic	Collector Current- Continuous	16	Α
Ісм	Collector Current- Continuous	30	Α
I <sub>B</sub>	Base Current- Continuous	8	Α
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃	65	W
Тл	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

10-23 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> = 2A			3.0	V			
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 8A; I <sub>B</sub> =2A			1.5	V			
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 1500V; I <sub>E</sub> = 0			1.0	mA			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7V; I <sub>C</sub> = 0			50	uA			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 8A; V <sub>CE</sub> = 5V	6		12				
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = 0.1A; V <sub>CE</sub> = 10V		3		MHz			
Switching ti	mes								
t <sub>stg</sub>	Storage Time	1 - 90 1 - 201 - 40			3.0	μ <b>S</b>			
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 8A , I <sub>B1</sub> =2A; I <sub>B2</sub> = -4A;			0.2	μ \$			

t <sub>stg</sub>	Storage Time	I <sub>C</sub> = 8A , I <sub>B1</sub> =2A; I <sub>B2</sub> = -4A;		3.0	μS
t <sub>f</sub>	Fall Time			0.2	μS

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